AZ



In the Claims

Please amend claims 3, 7, 9-16 as follows:

3. (Amended) An etching agent for copper according to Claim 1, wherein [the] a concentration of said potassium hydrogen peroxomonosulfate falls within a range of 0.08 to 2.0 met/l.

7. (Amended) An etching agent for a laminated film of a titanium film and a copper film comprising an aqueous solution containing a peroxomonosulfate salt, hydrofluoric acid, and one of hydrochloric acid [or] and a chloride.

- 9. (Amended) An etching agent for a laminated film of a titanium film and a copper film according to Claim 7, wherein said peroxosulfate salt comprises [any one or more compounds] a compound selected from KHSO₅, NaHSO₅, $K_2S_2O_8$, $Na_2S_2O_8$ and $(NH_4)_2S_2O_8$.
- 10. (Amended) An etching agent for a laminated film of a titanium film and a copper film according to Claim 7, wherein said chloride comprises one of an alkali metal chloride [or] and ammonium chloride.
- 11. (Amended) An etching agent for a laminated film of a titanium film and a copper film according to Claim 8, wherein said peroxosulfate salt comprises [any one or more compounds] a compound selected from KHSO₅, NaHSO₅, $K_2S_2O_8$, $Na_2S_2O_8$ and $(NH_4)_2S_2O_8$.
- 12. (Amended) An etching agent for a laminated film of a titanium film and a copper film according to Claim 8, wherein said fluoride comprises one of an alkali metal fluoride [or] and ammonium fluoride.
- 13. (Amended) A method for manufacturing an electronic device substrate comprising[the steps of]: depositing a copper film on the substrate; forming a given pattern on [the] a surface of the copper film; and etching the copper film using an etching agent comprising an agreeous solution containing potassium hydrogen peroxomonosulfate to form a copper wiring with a given pattern.
- 14. (Amended) A method for manufacturing an electronic device substrate comprising[the steps of] forming a mask with a given pattern on [the] a surface of a laminated film prepared by sequentially depositing one of a titanium [or] and titanium

alloy film, and a copper film on a substrate; and etching the laminated film [comprising the titanium or titanium alloy film and the copper film] using [either] one of an [ethcing] etching agent comprising an aqueous solution containing potassium hydrogen peroxomonosulfate and hydrofluoric aid, an etching agent comprising an aqueous solution containing a perbxosulfate salt and one of hydrochloric acid [or] and a chloride, [or] and an etching agent comprising an aqueous solution containing a peroxosulfate salt and a fluoride to form a laminated wiring with the given pattern.

15. / (Amended) An electronic device comprising an electronic device substrate prepared by a manufacturing method comprising the steps of: depositing a copper film on a substrate; forming a mask with a given pattern on the copper film; and etching the copper film using an etching agent comprising an aqueous solution containing potassium hydrogen peroxomonosulfate to form a copper wiring with a given pattern.

16. L (Amended) An electronic device comprising an electronic device substrate manufactured by a manufacturing method comprising[the steps of]: forming a mask with a given pattern on a laminated film prepared by sequentially depositing one of a tita/hium [or] and titanium alloy film and a copper film on a substrate; and etching the laminated film [of the titanium or titanium alloy film and the copper film] using [either] one of an etching agent comprising an aqueous solution containing potassium hydrogen peroxomonosulfate and hydrofluoric acid, an etching agent comprising an aqueous solution containing a peroxosulfate salt, hydrofluoric acid, and one of hydrochloric acid [or] and a chloride, [or] and an etching agent comprising an aqueous solution containing a peroxosulfate salt and a fluoride to from a laminated wiring with the given pattern.

Respectfully submitted.

Gustavo Siller, Jr.

Registration No. 32,305 Attorney for Applicants

BRINKS HOFER GILSON & LIONE P.O. BOX 10395 CHICAGO, ILLINOIS 60610 (312) 321-4200

